



**THE DATASHEET OF  
SBRT4U30LP-7**



## Product Summary

$V_{RRM}$ (V)	$I_o$ (A)	$V_F(MAX)$ (V) @ +25°C	$I_R(MAX)$ (mA) @ +25°C
30	4	0.5	0.1

## Description and Applications

The DIODES™ SBRT4U30LP provides very low  $V_F$  and excellent reverse leakage stability at high temperatures. It is ideal for use as bypass diode and rectifier, freewheel diode or blocking diode in applications such as:

- Solar panels
- Blocking diodes
- Bypass diodes
- Boost diodes
- Recirculating diodes

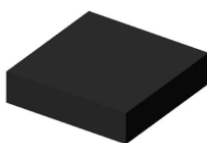
## Features and Benefits

- Patented TrenchSBR® technology provides superior avalanche capability versus schottky diodes, ensuring more rugged and reliable end applications.
- Reduced ultra-low forward voltage drop ( $V_F$ ). Better efficiency and cooler operation.
- Reduced high temperature reverse leakage. Increased reliability against thermal runaway failure in high temperature operation.
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at <https://www.diodes.com/products/automotive/automotive-products/>.**
- **This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. <https://www.diodes.com/quality/product-definitions/>**

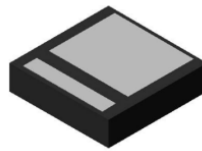
## Mechanical Data

- Package: U-DFN2020-2
- Package Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - NiPdAu over Copper Leadframe Solderable per MIL-STD-202, Method 208 (e4)
- Polarity: See Below
- Weight: 6.757mg (Approximate)

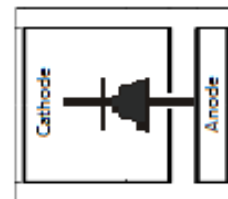
U-DFN2020-2 (Type B)



Top View



Bottom View



Top View  
Internal Schematic

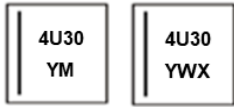
## Ordering Information (Note 4)

Part Number	Package	Packing	
		Qty.	Carrier
SBRT4U30LP-7	U-DFN2020-2 (Type B)	3,000	Tape & Reel

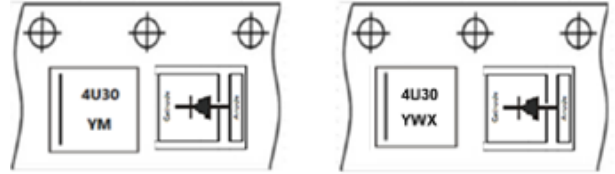
- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

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**Marking Information**



4U30 = Product Type Marking Code  
 YM & YWX= Date Code Marking  
 Y= Year (ex: J = 2022)  
 M = Month (ex: 8 = August)  
 W = Week Code  
 X = Internal Code  
 Bar = Cathode



Date Code Key

<b>Year</b>	2014	...	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
<b>Code</b>	B	...	J	K	L	M	N	O	P	R	S	T
<b>Month</b>	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
<b>Code</b>	1	2	3	4	5	6	7	8	9	O	N	D
<b>Week</b>	1-26					27-52					53	
<b>Code</b>	A-Z					a-z					z	
<b>Internal Code</b>	Sun	Mon	Tue	Wed	Thu	Fri	Sat					
<b>Code</b>	T	U	V	W	X	Y	Z					

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	30	V
Working Peak Reverse Voltage	V <sub>RWM</sub>		
DC Blocking Voltage	V <sub>RM</sub>		
Average Rectified Output Current	I <sub>O</sub>	4	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	45	A

**Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Case (Note 5)	R <sub>θJC</sub>	5	°C/W
Typical Thermal Resistance Junction to Ambient (Note 5)	R <sub>θJA</sub>	65	°C/W
Operating Temperature Range	T <sub>J</sub>	V <sub>R</sub> ≤ 80% V <sub>RRM</sub>	-55 to +150
		V <sub>R</sub> ≤ 50% V <sub>RRM</sub>	≤ +175
		DC Forward Mode (Note 7)	≤ +200
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Forward Voltage Drop (Note 6)	V <sub>F</sub>	—	—	0.5	V	I <sub>F</sub> = 4A, T <sub>J</sub> = +25°C
Leakage Current (Note 6)	I <sub>R</sub>	—	—	100	μA	V <sub>R</sub> = 30V, T <sub>J</sub> = +25°C
		—	5	—	mA	V <sub>R</sub> = 30V, T <sub>J</sub> = +125°C

Notes: 5. Device mounted on FR-4 PCB pad layout 1-inch 2oz copper.  
 6. Short duration pulse test used to minimize self-heating effect.  
 7. Maximum junction temperature guaranteed for two hours.

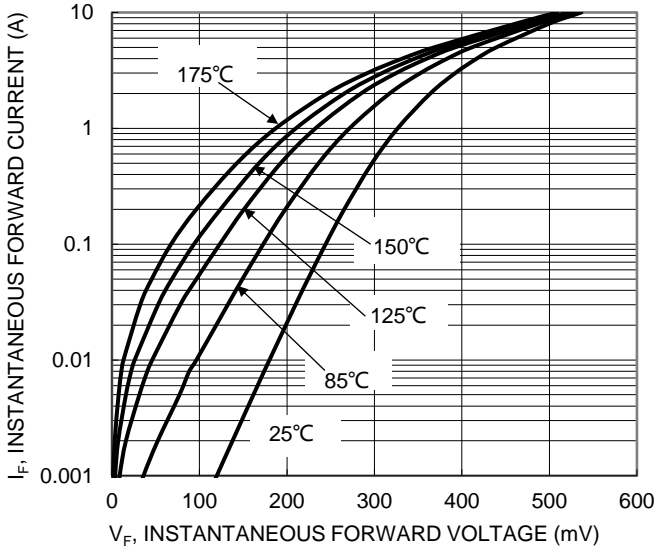


Figure 1. Typical Forward Characteristics

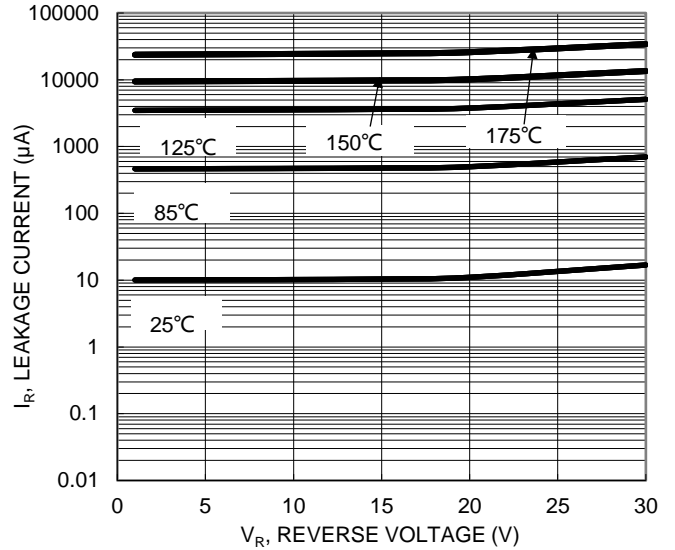


Figure 2. Typical Reverse Characteristics

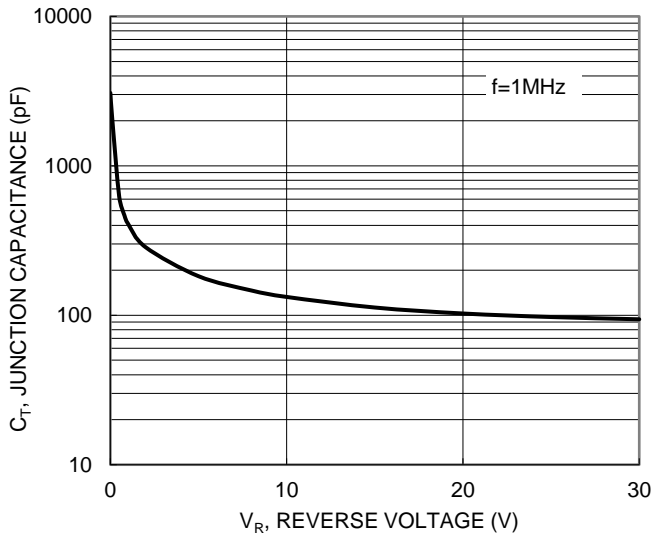


Figure 3. Typical Junction Capacitance

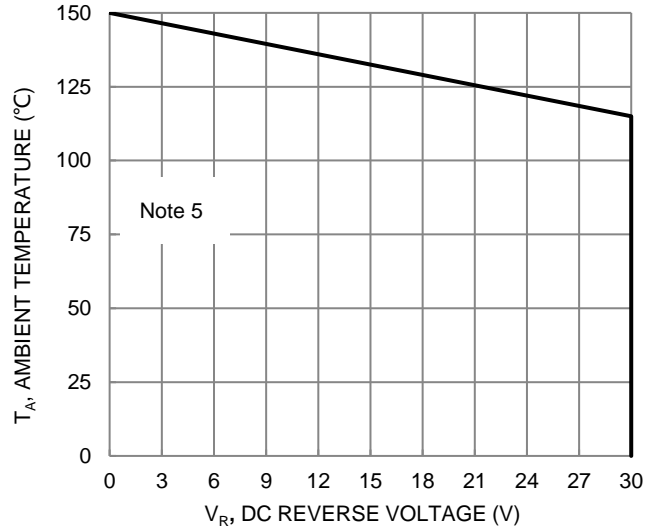


Figure 4. Operating Temperature Derating

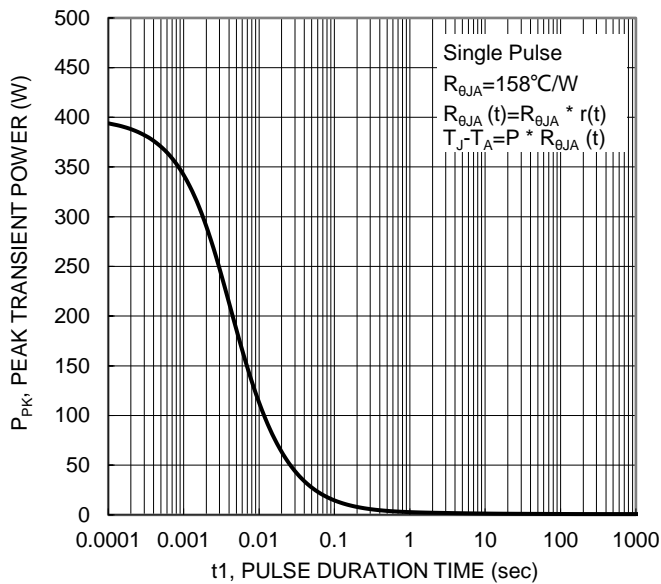


Figure 5. Single Pulse Maximum Power Dissipation

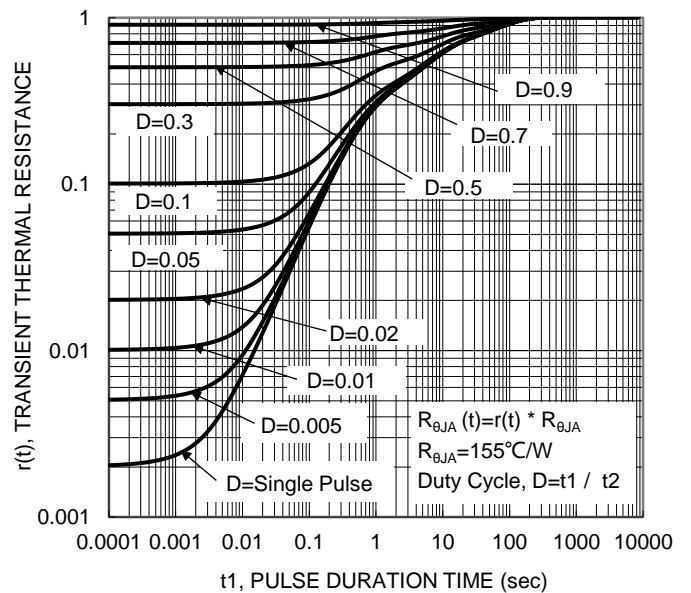
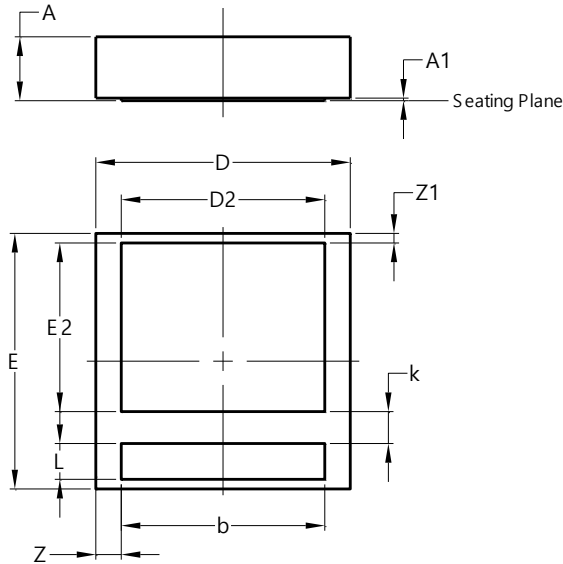


Figure 6. Transient Thermal Resistance

**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**U-DFN2020-2 (Type B)**

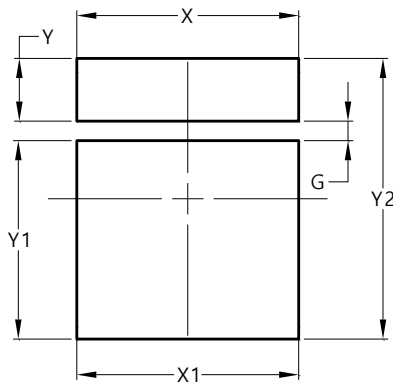


U-DFN2020-2 (Type B)			
Dim	Min	Max	Typ
A	0.47	0.53	0.50
A1	0.00	0.05	0.02
b	1.55	1.65	1.60
D	1.95	2.05	2.00
D2	1.50	1.70	1.60
E	1.95	2.05	2.00
E2	1.22	1.42	1.32
k	0.25 BSC		
L	0.23	0.33	0.28
Z	0.20 BSC		
Z1	0.075 BSC		
All Dimensions in mm			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**U-DFN2020-2 (Type B)**



Dimensions	Value (in mm)
G	0.150
X	1.700
X1	1.700
Y	0.480
Y1	1.520
Y2	2.150

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